

RGWX5TS65DHR

650V 75A Field Stop Trench IGBT

V _{CES}	650V
I _{C (100°C)}	75A
V _{CE(sat) (Typ.)}	1.5V
P _D	348W

Features

- 1) AEC-Q101 Qualified
- 2) Low Collector Emitter Saturation Voltage
- 3) Low Switching Loss & Soft Switching
- 4) Built in Very Fast & Soft Recovery FRD
- 5) Pb free Lead Plating ; RoHS Compliant

Application

Automotive

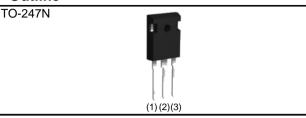
On & Off Board Chargers

DC-DC Converters

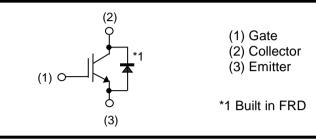
PFC

Industrial Inverter

Outline



Inner Circuit



Packaging Specifications

	Packaging	Tube
	Reel Size (mm)	-
Tuno	Tape Width (mm)	-
Туре	Basic Ordering Unit (pcs)	450
	Packing Code	C11
	Marking	RGWX5TS65D

•Absolute Maximum Ratings (at T_c = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V _{CES}	650	V
Gate - Emitter Voltage		V _{GES}	±30	V
Collector Current	$T_{\rm C} = 25^{\circ}{\rm C}$	Ι _C	132	А
Collector Current	$T_{\rm C} = 100^{\circ}{\rm C}$	Ι _C	81	Α
Pulsed Collector Current		I _{CP} ^{*1}	300	А
Diode Forward Current	$T_{\rm C} = 25^{\circ}{\rm C}$	١ _F	73	Α
	$T_{\rm C} = 100^{\circ}{\rm C}$	١ _F	43	А
Diode Pulsed Forward Current		I _{FP} ^{*1}	300	А
Devuer Dissingtion	$T_{\rm C} = 25^{\circ}{\rm C}$	P _D	348	W
Power Dissipation	$T_{\rm C} = 100^{\circ}{\rm C}$	P _D	174	W
Operating Junction Temperature		T _j	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

*1 Pulse width limited by T_{jmax.}

RGWX5TS65DHR

•Thermal Resistance

Deremeter	Sumbol	Values			Linit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal Resistance IGBT Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	0.43	°C/W
Thermal Resistance Diode Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	0.93	°C/W

●IGBT Electrical Characteristics (at T_i = 25°C unless otherwise specified)

Parameter	Symbol Conditions -		Values			Unit
Farameter			Min.	Тур.	Max.	
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_{\rm C}$ = 10µA, $V_{\rm GE}$ = 0V	650	-	-	V
Collector Cut - off Current	I _{CES}	$V_{CE} = 650 V, V_{GE} = 0 V$	-	-	10	μA
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30 V$, $V_{CE} = 0 V$	-	-	±200	nA
Gate - Emitter Threshold Voltage	V _{GE(th)}	V _{CE} = 5V, I _C = 50.4mA	5.0	6.0	7.0	V
Collector - Emitter Saturation Voltage	V _{CE(sat)}	$I_{C} = 75A, V_{GE} = 15V,$ $T_{j} = 25^{\circ}C$ $T_{j} = 175^{\circ}C$	-	1.5 1.85	1.9 -	V

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•IGBT Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Deremeter	Conditions		L La M				
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Input Capacitance	C _{ies}	V _{CE} = 30V,	-	5980	-		
Output Capacitance	C _{oes}	V _{GE} = 0V,	-	156	-	pF	
Reverse transfer Capacitance	C _{res}	f = 1MHz	-	118	-		
Total Gate Charge	Q_g	V _{CE} = 400V,	-	213	-		
Gate - Emitter Charge	Q_{ge}	I _C = 75A,	-	42	-	nC	
Gate - Collector Charge	Q_{gc}	V _{GE} = 15V	-	82	-		
Turn - on Delay Time	t _{d(on)}		-	62	-		
Rise Time	t _r	I _C = 37.5A, V _{CC} = 400V, V _{GE} = 15V, R _G = 10Ω,	-	17	-	ns	
Turn - off Delay Time	t _{d(off)}	$T_i = 25^{\circ}C$	-	237	-		
Fall Time	t _f	Inductive Load	-	35	-		
Turn - on Switching Loss	Eon	*E _{on} include diode reverse recovery	-	0.83	-	ml	
Turn - off Switching Loss	E_{off}	,	-	0.76	-	mJ	
Turn - on Delay Time	t _{d(on)}		-	57	-		
Rise Time	t _r	$I_{C} = 37.5A, V_{CC} = 400V,$ $V_{GE} = 15V, R_{G} = 10\Omega,$	-	17	-]	
Turn - off Delay Time	t _{d(off)}	$T_i = 175^{\circ}C$	-	263	-	ns	
Fall Time	t _f	Inductive Load	-	66	-		
Turn - on Switching Loss	E _{on}	*E _{on} include diode reverse recovery	-	0.83	-	~ l	
Turn - off Switching Loss	E _{off}		-	0.98	-	mJ	
Reverse Bias Safe Operating Area	RBSOA	$\begin{split} I_{C} &= 300 \text{A}, \ V_{CC} = 520 \text{V}, \\ V_{P} &= 650 \text{V}, \ V_{GE} = 15 \text{V}, \\ R_{G} &= 100 \Omega, \ T_{j} = 175^{\circ} \text{C} \end{split}$	FU	ILL SQUA	RE	-	

•FRD Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Parameter	Cumbal	Conditions	Values			Unit
Parameter	Symbol		Min.	Тур.	Max.	Unit
		I _F = 40A,				
Diode Forward Voltage	V_{F}	T _j = 25°C	-	1.45	1.9	V
		T _j = 175°C	-	1.55	-	
Diode Reverse Recovery Time	t _{rr}		-	92	-	ns
Diode Peak Reverse Recovery Current	I _{rr}	I _F = 37.5A, V _{CC} = 400V,	-	8.9	-	A
Diode Reverse Recovery Charge	Q _{rr}	di _F /dt = 200A/µs, T _j = 25°C	-	0.45	-	μC
Diode Reverse Recovery Energy	Err		-	14.5	-	μJ
Diode Reverse Recovery Time	t _{rr}	I _F = 37.5A, V _{CC} = 400V, di _F /dt = 200A/µs, T _j = 175°C	-	151	-	ns
Diode Peak Reverse Recovery Current	I _{rr}		-	11.8	-	A
Diode Reverse Recovery Charge	Q _{rr}		-	1.04	-	μC
Diode Reverse Recovery Energy	E _{rr}		-	45.9	-	μJ

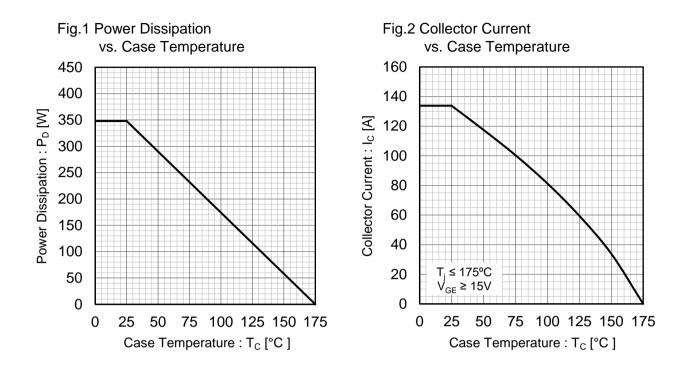
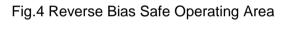
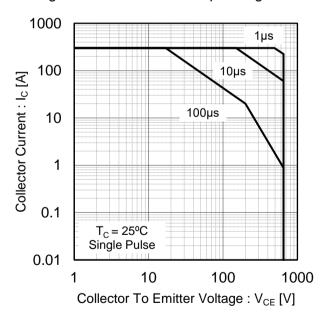
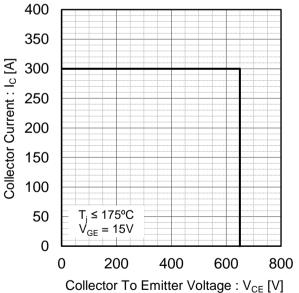


Fig.3 Forward Bias Safe Operating Area







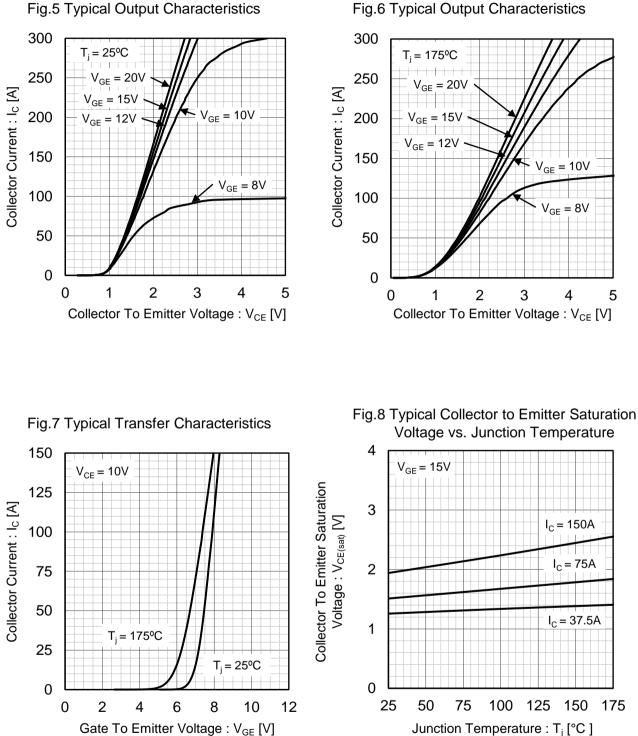
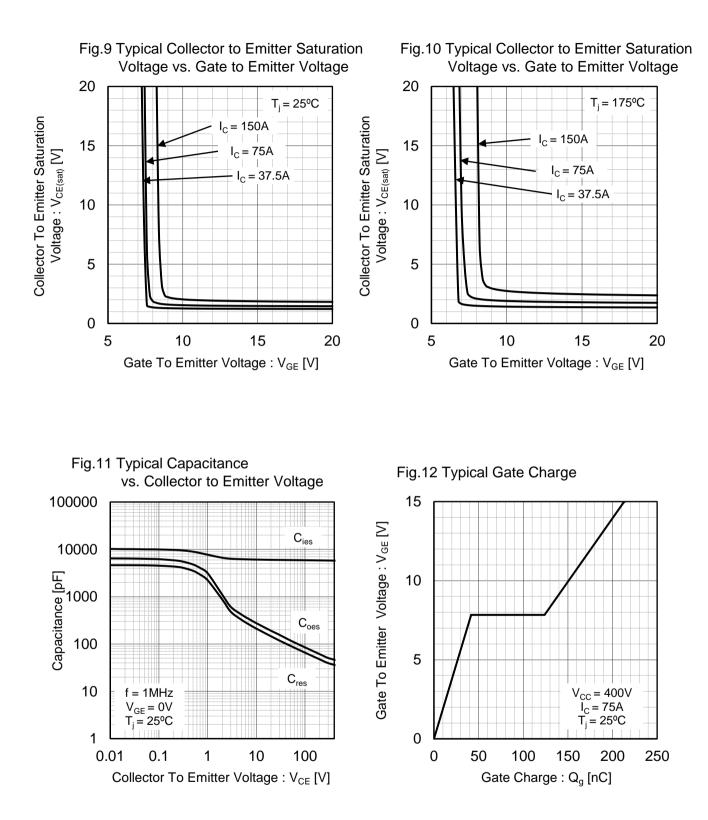
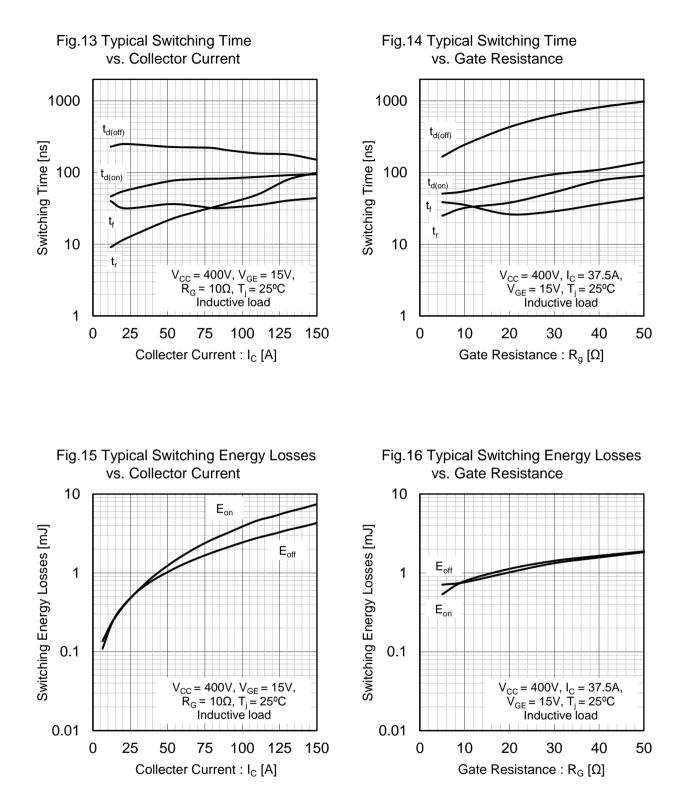
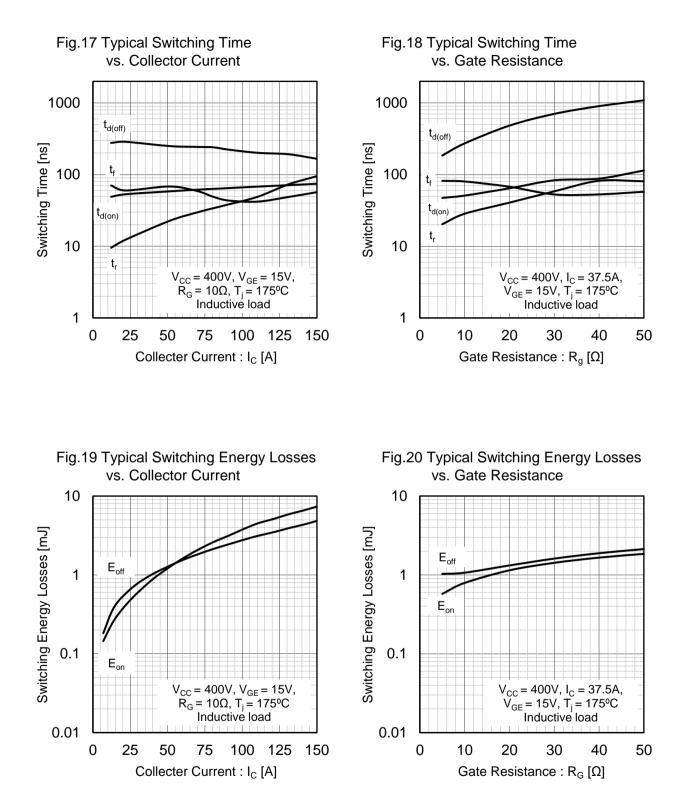
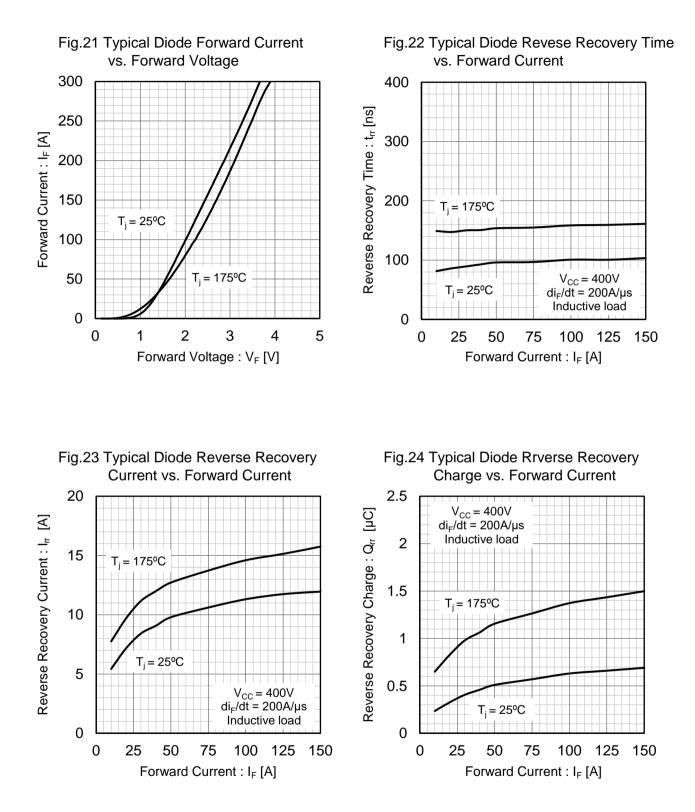


Fig.6 Typical Output Characteristics









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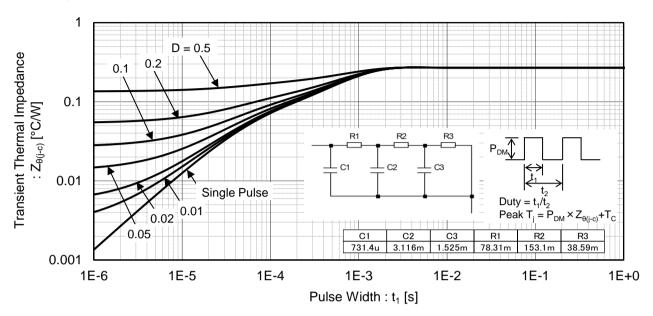
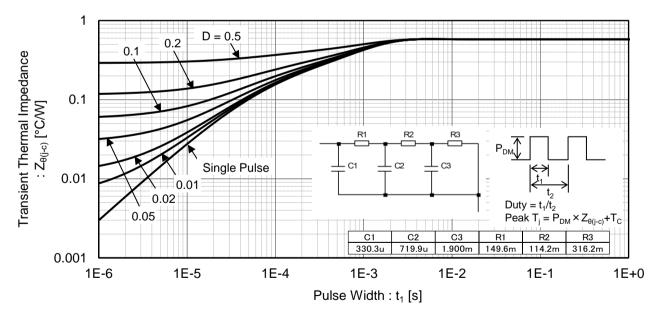


Fig.25 Typical IGBT Transient Thermal Impedance

Fig.26 Typical Diode Transient Thermal Impedance



Inductive Load Switching Circuit and Waveform

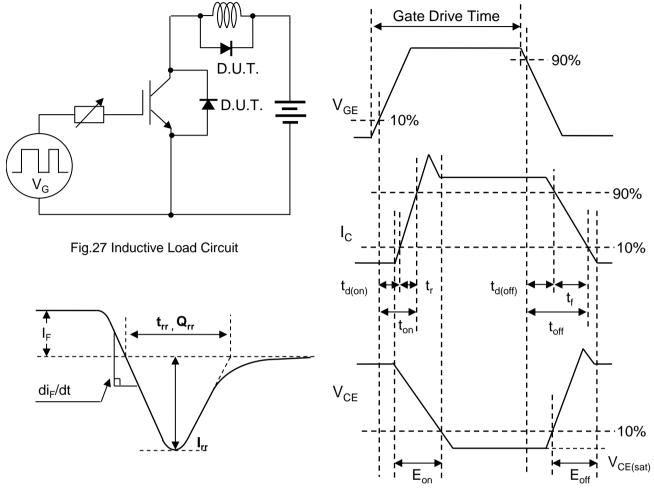


Fig.29 Diode Reverse Recovery Waveform

Fig.28 Inductive Load Waveform



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